## Larry A Coldren

## List of Publications by Citations

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105<br/>papers2,289<br/>citations22<br/>h-index45<br/>g-index128<br/>ext. papers2,835<br/>ext. citations3.6<br/>avg, IF4.97<br/>L-index

#	Paper	IF	Citations
105	2012,		632
104	A fully reconfigurable photonic integrated signal processor. <i>Nature Photonics</i> , <b>2016</b> , 10, 190-195	33.9	195
103	High Performance InP-Based Photonic ICsA Tutorial. <i>Journal of Lightwave Technology</i> , <b>2011</b> , 29, 554-57	04	129
102	Submilliamp threshold vertical-cavity laser diodes. <i>Applied Physics Letters</i> , <b>1990</b> , 57, 1605-1607	3.4	99
101	Efficient, High-Data-Rate, Tapered Oxide-Aperture Vertical-Cavity Surface-Emitting Lasers. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2009</b> , 15, 704-715	3.8	7°
100	An integrated parity-time symmetric wavelength-tunable single-mode microring laser. <i>Nature Communications</i> , <b>2017</b> , 8, 15389	17.4	63
99	High-speed InGaAs/GaAs strained multiple quantum well lasers with low damping. <i>Applied Physics Letters</i> , <b>1991</b> , 58, 2326-2328	3.4	60
98	. Journal of Lightwave Technology, <b>2008</b> , 26, 209-216	4	52
97	Two-Dimensional Optical Beam Steering With InP-Based Photonic Integrated Circuits. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2013</b> , 19, 6100212-6100212	3.8	48
96	Highly integrated optical heterodyne phase-locked loop with phase/frequency detection. <i>Optics Express</i> , <b>2012</b> , 20, 9736-41	3.3	44
95	Advanced InP Photonic Integrated Circuits for Communication and Sensing. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2018</b> , 24, 1-12	3.8	39
94	Large coherent acoustic-phonon oscillation observed in InGaN/GaN multiple-quantum wells. <i>Applied Physics Letters</i> , <b>1999</b> , 75, 1249-1251	3.4	38
93	Nonselective etching of GaAs/AlGaAs double heterostructure laser facets by Cl2 reactive ion etching in a load-locked system. <i>Applied Physics Letters</i> , <b>1987</b> , 51, 719-721	3.4	33
92	40Gbit/s coherent optical receiver using a Costas loop. <i>Optics Express</i> , <b>2012</b> , 20, B197-203	3.3	32
91	High Output Saturation and High-Linearity Uni-Traveling-Carrier Waveguide Photodiodes. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 149-151	2.2	32
90	Highly Linear Coherent Receiver With Feedback. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 940-942	2.2	32
89	Towards chip-scale optical frequency synthesis based on optical heterodyne phase-locked loop.  Optics Express, 2017, 25, 681-695	3.3	30

88	Programmable Photonic Lattice Filters in InGaAsPIhP. IEEE Photonics Technology Letters, 2010, 22, 109-	-11.12	26	
87	Angled etching of GaAs/AlGaAs by conventional Cl2 reactive ion etching. <i>Applied Physics Letters</i> , <b>1988</b> , 53, 2549-2551	3.4	25	
86	40-Gb/s Widely Tunable Low-Drive-Voltage Electroabsorption-Modulated Transmitters. <i>Journal of Lightwave Technology</i> , <b>2007</b> , 25, 239-248	4	24	
85	Channeling as a mechanism for dry etch damage in GaN. <i>Applied Physics Letters</i> , <b>2000</b> , 76, 3941-3943	3.4	24	
84	High verticality InP/InGaAsP etching in Cl2/H2/Ar inductively coupled plasma for photonic integrated circuits. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , <b>2011</b> , 29, 011016	1.3	23	
83	. IEEE Journal of Selected Topics in Quantum Electronics, <b>2019</b> , 25, 1-7	3.8	22	
82	Folded-cavity transverse junction stripe surface-emitting laser. <i>Applied Physics Letters</i> , <b>1989</b> , 55, 1053-	1055	22	
81	40-Gb/s Widely Tunable Transceivers. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2007</b> , 13, 3-14	3.8	20	
80	. Journal of Lightwave Technology, <b>2021</b> , 39, 520-531	4	20	
79	Monolithically Integrated Gain-Flattened Ring Mode-Locked Laser for Comb-Line Generation. <i>IEEE Photonics Technology Letters</i> , <b>2012</b> , 24, 131-133	2.2	19	
78	A Photonic Temporal Integrator With an Ultra-Long Integration Time Window Based on an InP-InGaAsP Integrated Ring Resonator. <i>Journal of Lightwave Technology</i> , <b>2014</b> , 32, 3654-3659	4	17	
77	Indium Phosphide Photonic Integrated Circuits for Coherent Optical Links. <i>IEEE Journal of Quantum Electronics</i> , <b>2012</b> , 48, 279-291	2	17	
76	Monolithic Integration of a High-Speed Widely Tunable Optical Coherent Receiver. <i>IEEE Photonics Technology Letters</i> , <b>2013</b> , 25, 1077-1080	2.2	17	
75	A Monolithically Integrated ACP-OPLL Receiver for RF/Photonic Links. <i>IEEE Photonics Technology Letters</i> , <b>2011</b> , 23, 1475-1477	2.2	15	
74	Linear Coherent Receiver based on a Broadband and Sampling Optical Phase-Locked Loop 2007,		15	
73	High-Power Indium Phosphide Photonic Integrated Circuits. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2019</b> , 25, 1-10	3.8	14	
72	Polarization degenerate solid-state cavity quantum electrodynamics. <i>Physical Review B</i> , <b>2015</b> , 91,	3.3	13	
71	40 Gb/s Field-Modulated Wavelength Converters for All-Optical Packet Switching. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2009</b> , 15, 494-503	3.8	13	

70	Indium Phosphide Photonic Integrated Circuits for Free Space Optical Links. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2018</b> , 24,	3.8	12
69	High-efficiency, high-speed VCSELs for optical interconnects. <i>Applied Physics A: Materials Science and Processing</i> , <b>2009</b> , 95, 1033-1037	2.6	12
68	Reduced temperature sensitivity of the wavelength of a diode laser in a stress-engineered hydrostatic package. <i>Applied Physics Letters</i> , <b>1996</b> , 69, 455-457	3.4	12
67	Holographic realization of hexagonal two dimensional photonic crystal structures with elliptical geometry. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , <b>2010</b> , 28, 1030-1038	1.3	11
66	SOA Gate Array Recirculating Buffer for Optical Packet Switching 2008,		11
65	Investigation of tilted superlattices for quantum-wire laser applications. <i>Applied Physics Letters</i> , <b>1991</b> , 59, 3015-3017	3.4	11
64	Multivalued Stability Map of an Injection-Locked Semiconductor Laser. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2013</b> , 19, 1501408-1501408	3.8	10
63	Photonic Integrated Circuits for microwave photonics <b>2010</b> ,		10
62	1.5mW/Gbps Low Power Optical Interconnect Transmitter Exploiting High-Efficiency VCSEL and CMOS Driver <b>2008</b> ,		10
61	Separate Absorption and Modulation Mach-Zehnder Wavelength Converter. <i>Journal of Lightwave Technology</i> , <b>2008</b> , 26, 91-98	4	10
60	A Wavelength Tunable Optical Buffer Based on Self-Pulsation in an Active Microring Resonator. Journal of Lightwave Technology, <b>2016</b> , 34, 3466-3472	4	10
59	Indium Phosphide Photonic Integrated Circuits: Technology and Applications 2018,		10
58	Wafer-fused AlGaAs/GaAs/GaN heterojunction bipolar transistor. <i>Applied Physics Letters</i> , <b>2003</b> , 82, 820-	83.2	9
57	Lasing characteristics of a continuous-wave operated folded-cavity surface-emitting laser. <i>Applied Physics Letters</i> , <b>1990</b> , 56, 2267-2269	3.4	9
56	Widely Tunable Separate Absorption and Modulation Wavelength Converter With Integrated Microwave Termination. <i>Journal of Lightwave Technology</i> , <b>2008</b> , 26, 938-944	4	8
55	Application of thin silicon films to closed-tube Si and Zn diffusion in GaAs and AlxGa1\( \text{As}\). <i>Journal of Applied Physics</i> , <b>1988</b> , 63, 5541-5547	2.5	8
54	Spurious-Free Dynamic Range in Photonic Integrated Circuit Filters With Semiconductor Optical Amplifiers. <i>IEEE Journal of Quantum Electronics</i> , <b>2012</b> , 48, 269-278	2	7
53	A 120-GHz All-Digital InP HBT Optical Wavelength Synthesis IC. <i>IEEE Transactions on Microwave Theory and Techniques</i> , <b>2013</b> , 61, 570-580	4.1	7

52	An Integrated Heterodyne Optical Phase-locked Loop with Record Offset Locking Frequency 2014,		7
51	Monolithic Linewidth Narrowing of a Tunable SG-DBR Laser <b>2013</b> ,		7
50	InP/InGaAsP Flattened Ring Lasers With Low-Loss Etched Beam Splitters. <i>IEEE Photonics Technology Letters</i> , <b>2011</b> , 23, 573-575	2.2	7
49	Integrated 30GHz passive ring mode-locked laser with gain flattening filter 2010,		5
48	Single-chip integrated transmitters and receivers. <i>Optics Express</i> , <b>2012</b> , 20, B377-85	3.3	5
47	A Dynamic Measurement Technique for Third-Order Distortion in Optical Phase Modulators. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 170-172	2.2	5
46	High-Confinement Strained MQW for Highly Polarized High-Power Broadband Light Source. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 771-773	2.2	5
45	n-AlGaAs/p-GaAs/n-GaN heterojunction bipolar transistor wafer-fused at 550🛭 50 ீ C. <i>Applied Physics Letters</i> , <b>2003</b> , 83, 560-562	3.4	5
44	Impurity-induced disordering of AIGalnAs quantum wells by low temperature Zn diffusion. <i>Journal of Electronic Materials</i> , <b>1996</b> , 25, 565-569	1.9	5
43	First Monolithically Integrated Dual-Pumped Phase-Sensitive Amplifier Chip Based on a Saturated Semiconductor Optical Amplifier. <i>IEEE Journal of Quantum Electronics</i> , <b>2016</b> , 52, 1-12	2	4
42	Integrated Linewidth Reduction of a Tunable SG-DBR Laser <b>2013</b> ,		4
41	Realization of silicon nanopillar arrays with controllable sidewall profiles by holography lithography and a novel single-step deep reactive ion etching. <i>Materials Research Society Symposia Proceedings</i> , <b>2010</b> , 1258, 1		4
40	A Chip-Scale Heterodyne Optical Phase-Locked Loop with Low-Power Consumption 2017,		4
39	High-Power Integrated Indium Phosphide Transmitter for Free Space Optical Communications <b>2018</b> ,		4
38	Compact Low-Power Consumption Single-Mode Coupled Cavity Lasers. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2017</b> , 23, 1-9	3.8	3
37	Evolution of Chip-Scale Heterodyne Optical Phase-Locked Loops Toward Watt Level Power Consumption. <i>Journal of Lightwave Technology</i> , <b>2018</b> , 36, 258-264	4	3
36	Ultra-compact integrated coherent receiver for high linearity RF photonic links 2010,		3
35	Demonstration of a linear ultra-compact integrated coherent receiver <b>2010</b> ,		3

34	Increased Modal Overlap for Improved Sensitivity in a Monolithic Intracavity Chemical Sensor. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 1051-1053	2.2	3
33	Analysis of Sampled Optical Phase-Lock Loops <b>2007</b> ,		3
32	Wafer-fused n-AlGaAs/p-GaAs/n-GaN Heterojunction Bipolar Transistor with uid-GaAs Base-Collector Setback. <i>Materials Research Society Symposia Proceedings</i> , <b>2003</b> , 798, 92		3
31	Photonic Integrated Circuits for Precision Spectroscopy <b>2020</b> ,		3
30	Indium Phosphide Photonic Integrated Circuit Transmitter with Integrated Linewidth Narrowing for Laser Communications and Sensing <b>2018</b> ,		3
29	Integrated Indium Phosphide Transmitter for Free Space Optical Link 2018,		3
28	Efficient and Accurate Modeling of Multiwavelength Propagation in SOAs: A Generalized Coupled-Mode Approach. <i>Journal of Lightwave Technology</i> , <b>2016</b> , 34, 2188-2197	4	2
27	Wideband and Continuously Tunable Microwave Photonic Phase Shifter Based on an Active InP/InGaAsP Microring Resonator <b>2019</b> ,		2
26	Ultrafast electrical polarization modulation in VCSEL with asymmetric current injection 2014,		2
25	Large-scale InP photonic integrated circuit packaged with ball grid array for 2D optical beam steering <b>2013</b> ,		2
24	InP photonic integrated circuit with on-chip monitors for optical beam steering 2012,		2
23	A Heterodyne Optical Phase-locked Loop for Multiple Applications 2013,		2
22	Integrated coherent receiver for linear optical phase demodulation. <i>Microwave and Optical Technology Letters</i> , <b>2011</b> , 53, 2343-2345	1.2	2
21	Wide-dynamic-range, fast-response CBr4 doping system for molecular beam epitaxy. <i>Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics</i> , <b>2010</b> , 28, C3F10-C3F15	1.3	2
20	45 nm wavelength tuning range of an InP/InGaAsP photonic integrated tunable receiver. <i>Applied Physics Letters</i> , <b>1996</b> , 69, 3131-3133	3.4	2
19	INTREPID program: technology and architecture for next-generation, energy-efficient, hyper-scale data centers [Invited]. <i>Journal of Optical Communications and Networking</i> , <b>2021</b> , 13, 347	4.1	2
18	Gallium Arsenide Photonic Integrated Circuit Platform for Tunable Laser Applications. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2022</b> , 28, 1-9	3.8	2
17	Dual Laser Indium Phosphide Photonic Integrated Circuit for Integrated Path Differential Absorption Lidar. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2022</b> , 28, 1-8	3.8	2

## LIST OF PUBLICATIONS

16	Optical synthesis using Kerr frequency combs <b>2017</b> ,		1
15	Novel application of quantum well intermixing implant buffer layer to enable high-density photonic integrated circuits in InP <b>2009</b> ,		1
14	Periodic Loading and Selective Undercut Etching for High-Impedance Traveling-Wave Electroabsorption Modulators <b>2008</b> ,		1
13	Analysis of Digital System Performance in EAM-Based Photocurrent Driven Wavelength Converter. <i>IEEE Photonics Technology Letters</i> , <b>2007</b> , 19, 215-217	2.2	1
12	Effect Of AlGaN/GaN Strained Layer Superlattice Period On InGaN MQW Laser Diodes. <i>MRS Internet Journal of Nitride Semiconductor Research</i> , <b>2000</b> , 5, 14-19		1
11	SGDBR tunable laser on gallium arsenide for 1030 nm lidar applications <b>2021</b> ,		1
10	Heterogeneously Integrated O-band SG-DBR Lasers for Short Reach Analog Coherent Links 2021,		1
9	Integrated Micro-Photonics for Remote Earth Science Sensing (Impress) Lidar 2019,		1
8	Widely Tunable Integrated Laser Transmitter for Free Space Optical Communications 2018,		1
7	Effect of AlGaN/GaN Strained Layer Superlattice Period on InGaN MQW Laser Diodes. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 595, 1		O
6	A Review of Photonic Systems-on-Chip Enabled by Widely Tunable Lasers. <i>IEEE Journal of Quantum Electronics</i> , <b>2022</b> , 1-1	2	О
5	Highly Polarized Single-Chip ELED Sources Using Oppositely Strained MQW Emitters and Absorbers. <i>IEEE Photonics Technology Letters</i> , <b>2008</b> , 20, 1267-1269	2.2	
4	Transmission Line Characterization of Undercut-Ridge Traveling-Wave Electroabsorption Modulators. <i>IEEE Photonics Technology Letters</i> , <b>2008</b> , 20, 1302-1304	2.2	
3	The First Wafer-fused AlGaAs-GaAs-GaN Heterojunction Bipolar Transistor. <i>Materials Research Society Symposia Proceedings</i> , <b>2002</b> , 743, L12.10.1		
2	Improved Characteristics of InGaN Multi-Quantum-Well Laser Diodes Grown on Laterally Epitaxially Overgrown GaN on Sapphire. <i>Materials Research Society Symposia Proceedings</i> , <b>1999</b> , 595, 1		
1	Improved Characteristics of InGaN Multi-Quantum-Well Laser Diodes Grown on Laterally Epitaxially Overgrown GaN on Sapphire. <i>MRS Internet Journal of Nitride Semiconductor Research</i> , <b>2000</b> , 5, 8-13		